

NCE P-Channel Enhancement Mode Power MOSFET

Description

The NCE60P50 uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge .This device is well suited for high current load applications.

General Features

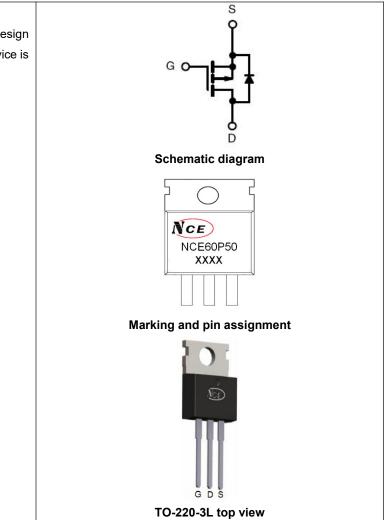
- V_{DS} =-60V,I_D =-50A
 R_{DS(ON)} <28mΩ @ V_{GS}=-10V
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high EAS
- Excellent package for good heat dissipation

Application

Load switch

100% UIS TESTED!

100% ΔVds TESTED!



Package Marking and Ordering Information

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Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE60P50	NCE60P50	TO-220-3L	-	-	-

Absolute Maximum Ratings (Tc=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	-60	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	Ι _D	-50	A
Drain Current-Continuous(Tc=100℃)	I _D (100℃)	-35	А
Pulsed Drain Current	І _{дм}	-150	А
Maximum Power Dissipation	PD	95	W
Derating factor		0.76	W/℃
Drain Source voltage slope	dv/dt	50	V/ns
Single pulse avalanche energy (Note 5)	E _{AS}	722	mJ
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C



Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	Rejc	1.31	°C/W
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Electrical Characteristics (Tc=25°C unless otherwise noted)

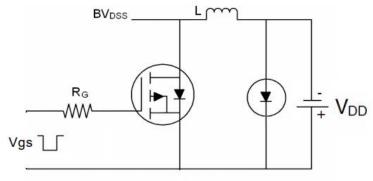
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	·					
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-60	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-60V,V _{GS} =0V	-	-	-1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)	I	1				
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =-250µA	-2	-2.6	-3.5	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-10V, I _D =-20A	-	23	28	mΩ
Gate resistance	Rg		-	3.3	-	Ω
Forward Transconductance	G FS	V _{DS} =-10V,I _D =-20A	-	25	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	Clss		-	6460	-	PF
Output Capacitance	Coss	V_{DS} =-25V, V_{GS} =0V,	-	719	-	PF
Reverse Transfer Capacitance	Crss	F=1.0MHz	-	535	-	PF
Switching Characteristics (Note 4)			·			
Turn-on Delay Time	t _{d(on)}		-	15	-	nS
Turn-on Rise Time	tr	V _{DD} =-30V, R _L =1.5Ω,	-	17	-	nS
Turn-Off Delay Time	t _{d(off)}	V _{GS} =-10V,R _G =3Ω	-	40	-	nS
Turn-Off Fall Time	t _f		-	45	-	nS
Total Gate Charge	Qg	V - 20 L - 20A	-	75		nC
Gate-Source Charge	Q _{gs}	V _{DS} =-30,I _D =-20A, V _{GS} =-10V	-	16		nC
Gate-Drain Charge	Q _{gd}	V _{GS} 10V	-	19		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-20A	-		-1.2	V
Diode Forward Current (Note 2)	ls		-	-	-50	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF =- 20A	-	50		nS
Reverse Recovery Charge	Qrr	di/dt = -100A/µs ^(Note3)	-	59		nC
Forward Turn-On Time	ton	Intrinsic turn-on time is negl	igible (turi	n-on is do	minated b	y LS+LD)

Notes:

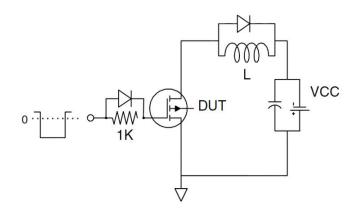
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, t \leq 10 sec.
- **3.** Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production
- **5.** Eas condition: Tj=25 $^\circ\!\!\mathrm{C}$,V_DD=-20V,V_G=-10V,L=1mH,Rg=25\Omega,I_{AS}=38A



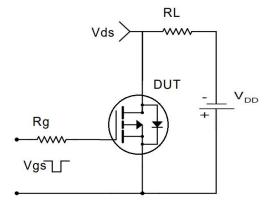
Test Circuit 1) E_{AS} test Circuit



2) Gate charge test Circuit

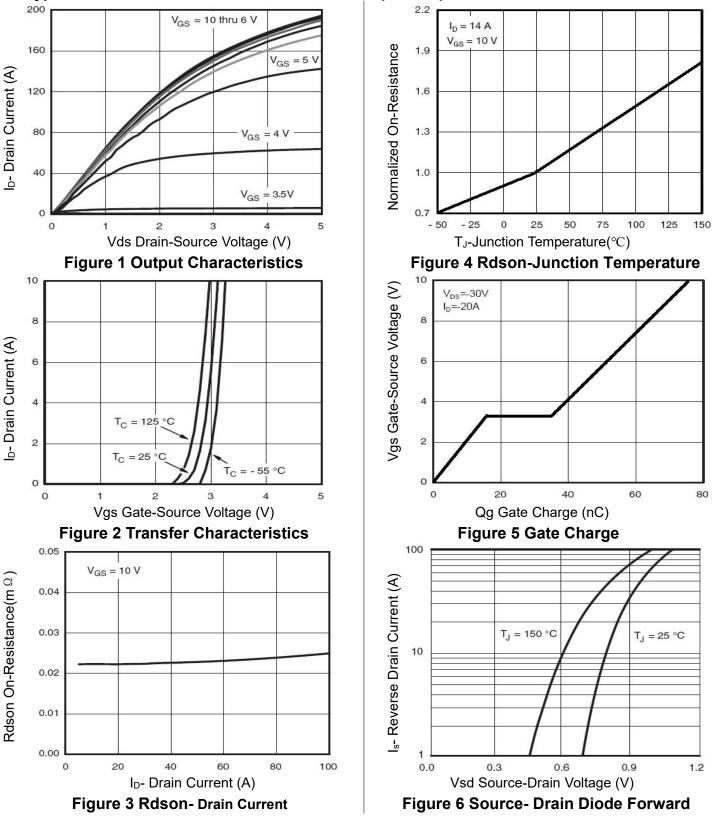


3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics (Curves)





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NCE60P50

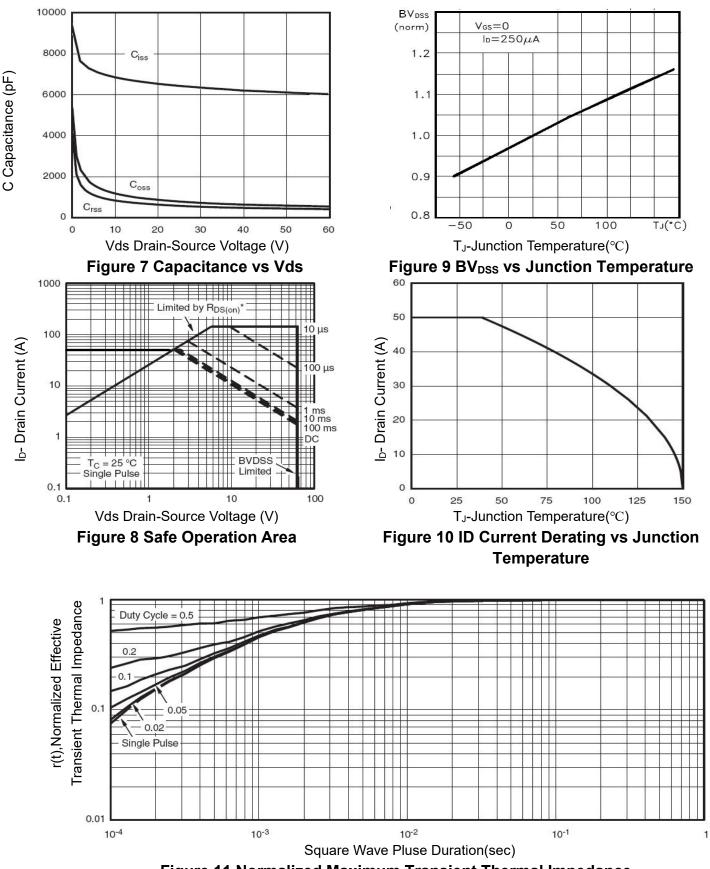
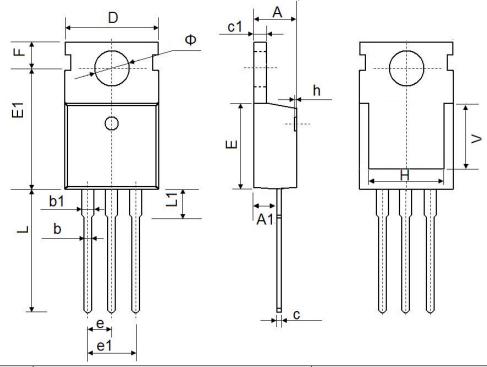


Figure 11 Normalized Maximum Transient Thermal Impedance



TO-220-3L Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.330	0.650	0.013	0.026	
c1	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
E	8.9500	9.750	0.352	0.384	
E1	12.650	12.950	0.498	0.510	
е	2.540	TYP.	0.100	TYP.	
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	7.500	7.500 REF.		REF.	
Ф	3.400	3.800	0.134	0.150	



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